

Journal of Semiconductors

Volume 33 Number 4 April 2012

SEMICONDUCTOR PHYSICS

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Anees A. Ansari, M. A. M. Khan, M. Alhoshan, S. A. Alrokayan, and M. S. Alsalhi

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Peng Bobo, Wang Fei, Liu Tao, Yang Zhenya, Wang Lianwei, Ricky K.Y. Fu, and Paul K. Chu

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Zhang Wenmin, Zhang Wei, Fu Jun, and Wang Yudong
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Tang Zhaohuan, Hu Gangyi, Chen Guangbing, Tan Kaizhou, Liu Yong, Luo Jun, and Xu Xueliang
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Huang Huixiang, Liu Zhangli, Hu Zhiyuan, Zhang Zhengxuan, Chen Ming, Bi Dawei, and Zou Shichang

(Continued on inside back cover)

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Liu Chunjuan, Liu Su, and Bai Yajie

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Hu Xueqing, Gong Zheng, Zhao Jinxin, Wang Lei, Yu Peng, and Shi Yin
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Li Yilei, Han Kefeng, Yan Na, Tan Xi, and Min Hao
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Chen Shuai, Li Hao, Shi Xiaobing, Yang Liqiong, Yang Zongren, Zhong Shiqiang, and Huang Lingyi
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Lou Wenfeng, Feng Peng, Wang Haiyong, and Wu Nanjian
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Liu Lianxi, Zhu Zhangming, and Yang Yintang
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Ye Qiang, Liu Jie, Yuan Bing, Lai Xinquan, and Liu Ning
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Yin Xizhen, Xiao Shimao, Jin Yuhua, Wu Qiwu, Ma Chengyan, and Ye Tianchun
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Ye Mao, Zhou Yumei, Wu Bin, and Jiang Jianhua
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Wang Chenwei, Liu Yuling, Niu Xinhuan, Tian Jianying, Gao Baohong, and Zhang Xiaoqiang
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Lin Xiaohui, Zhang Chibin, Ren Weisong, Jiang Shuyun, and Ouyang Quanhui